

SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

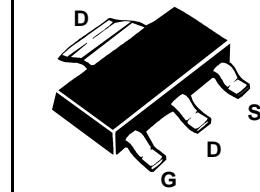
ISSUE 3 – OCTOBER 1995

ZVN2110G

FEATURES

- * 6A PULSE DRAIN CURRENT
- * FAST SWITCHING SPEED

PARTMARKING DETAIL - ZVN2110
COMPLEMENTARY TYPE - ZVP2110G



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE			UNIT
Drain-Source Voltage	V_{DS}	100			V
Continuous Drain Current at $T_{amb}=25^\circ C$	I_D	500			mA
Pulsed Drain Current	I_{DM}	6			A
Gate Source Voltage	V_{GS}	± 20			V
Power Dissipation at $T_{amb}=25^\circ C$	P_{tot}	2			W
Operating and Storage Temperature Range	$T_j:T_{stg}$	-55 to +150			°C

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	BV_{DS}	100			V	$I_D=1mA$, $V_{GS}=0V$
Gate-Source Threshold Voltage	$V_{GS(th)}$	0.8		2.4	V	$I_D=1mA$, $V_{DS}=V_{GS}$
Gate-Body Leakage	I_{GSS}		0.1	20	nA	$V_{GS}=\pm 20V$, $V_{DS}=0V$
Zero Gate Voltage Drain Current	I_{DSS}			1 100	μA	$V_{DS}=100V$, $V_{GS}=0$ $V_{DS}=80V$, $V_{GS}=0V$, $T=125^\circ C(2)$
On-State Drain Current(1)	$I_{D(on)}$	1.5	2		A	$V_{DS}=25V$, $V_{GS}=10V$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$			4	Ω	$V_{GS}=10V$, $I_D=1A$
Forward Transconductance (1)(2)	g_{fs}	250	350		mS	$V_{DS}=25V$, $I_D=1A$
Input Capacitance (2)	C_{iss}		59	75	pF	$V_{DS}=25V$, $V_{GS}=0V$, $f=1MHz$
Common Source Output Capacitance (2)	C_{oss}		16	25	pF	
Reverse Transfer Capacitance (2)	C_{rss}		4	8	pF	
Turn-On Delay Time (2)(3)	$t_{d(on)}$		4	7	ns	
Rise Time (2)(3)	t_r		4	8	ns	$V_{DD} \approx 25V$, $I_D=1A$
Turn-Off Delay Time (2)(3)	$t_{d(off)}$		8	13	ns	
Fall Time (2)(3)	t_f		8	13	ns	

DRAIN-SOURCE DIODE CHARACTERISTICS

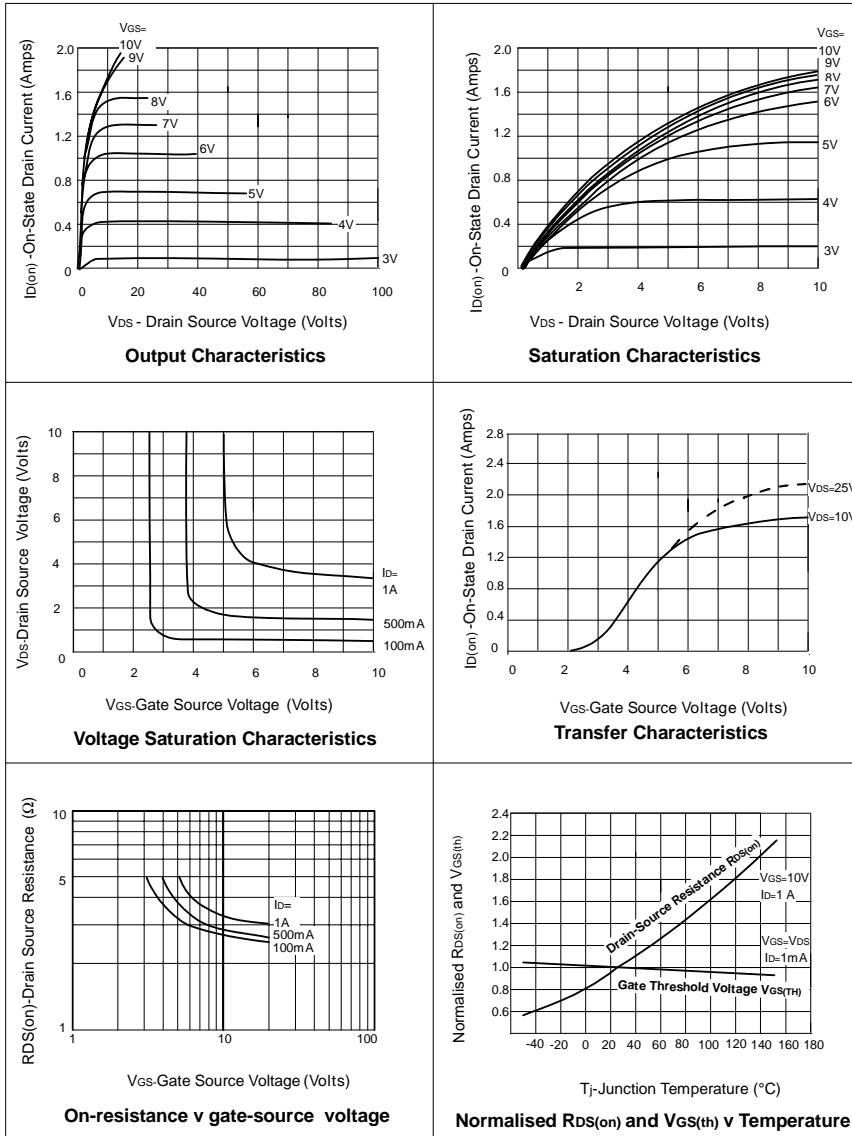
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Diode Forward Voltage (1)	V_{SD}		0.82		V	$I_S=0.32A$, $V_{GS}=0$
Reverse Recovery Time	T_{RR}		112		ns	$I_F=0.32A$, $V_{GS}=0$, $I_R=0.1A$

(1) Measured under pulsed conditions. Width=300μs. Duty cycle ≤2%

(2) Sample test.
(3) Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator

ZVN2110G

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS